





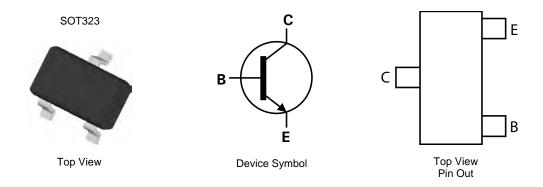
NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR IN SOT323

Features

- Low saturation voltage
- 500mW power dissipation
- I_C = 1A high Continuous Current
- Ideally suited for space / weight critical applications
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT323
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.006 grams (Approximate)



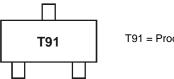
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZUMT491TA	T91	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com

Marking Information



T91 = Product Type Marking Code



ZUMT491

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Collector-Base Voltage	V_{CBO}	80	V	
Collector-Emitter Voltage	V _{CEO}	60	V	
Emitter-Base Voltage	V_{EBO}	7	V	
Continuous Collector Current	Ιc	1	A	
Peak Pulse Current	Ісм	2	A	
Base Current	l _Β	200	mA	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	500	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	250	°C/W
Thermal Resistance, Junction to Leads (Note 6)	R ₀ JL	350	°C/W
Operating and Storage Temperature Range	$T_{J,}T_{STG}$	-55 to +150	°C

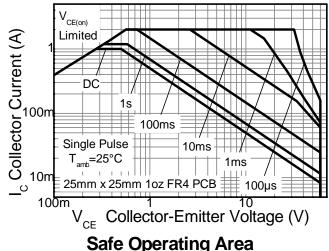
Notes:

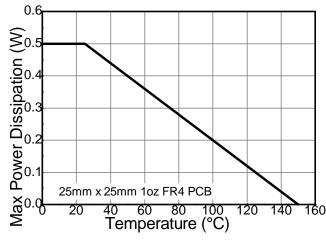
^{5.} For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; device measured when operating in steady state condition.

^{6.} Thermal resistance from junction to solder-point (at the end of the leads).



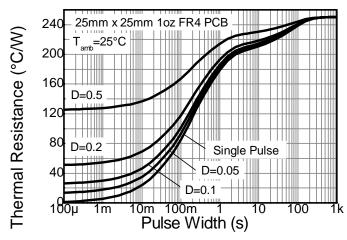
Thermal Characteristics and Derating Information

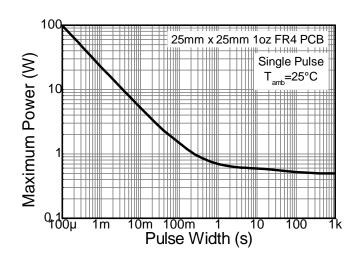




Safe Operating Area

Derating Curve





Transient Thermal Impedance

Pulse Power Dissipation



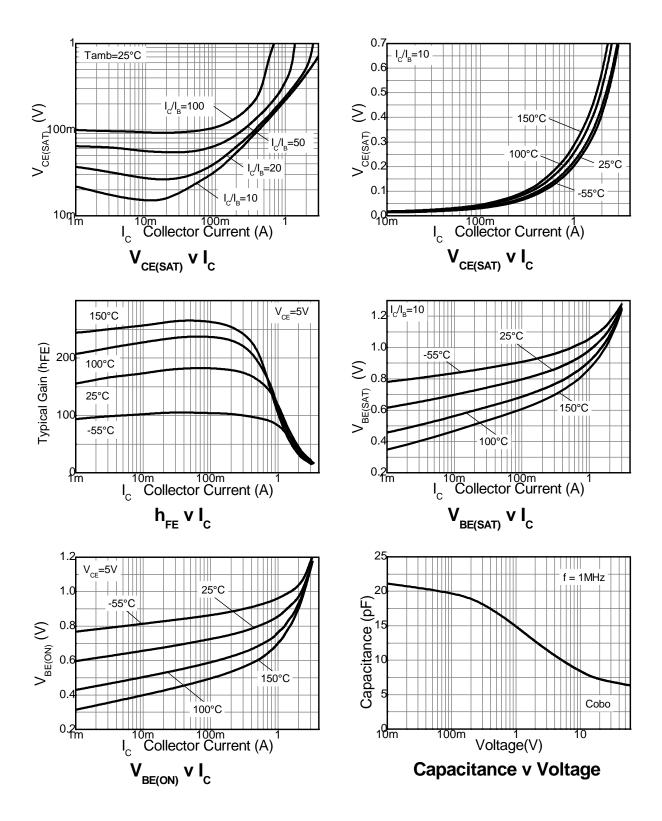
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS					
Collector-Base Breakdown Voltage	BV _{CBO}	80	_	V	$I_C = 100 \mu A, I_E = 0$
Collector-Emitter Breakdown Voltage (Note 7)	BV _{CEO}	60	_	V	I _C = 10mA, I _B = 0
Emitter-Base Breakdown Voltage	BV _{EBO}	7	_	V	$I_E = 100 \mu A, I_C = 0$
Collector Cutoff Current	I _{CBO}	_	100	nA	V _{CB} = 60V
Collector Cutoff Current	I _{CES}	_	100	nA	V _{CE} = 60V
Emitter Cutoff Current	I _{EBO}	_	100	nA	V _{EB} = 5V
ON CHARACTERISTICS (Note 7)					
DO 0		100			$I_{C} = 1 \text{mA}, V_{CE} = 5.0 \text{V}$
DC Current Gain	h _{FE}	100 80	300		$I_C = 500.0$ mA, $V_{CE} = 5.0$ V $I_C = 1.0$ A, $V_{CE} = 5.0$ V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	_	250 500	mV	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$ $I_C = 1.0 \text{A}, I_B = 100 \text{mA}$
Base-Emitter Saturation Voltage	V _{BE(sat)}	_	1100	mV	I _C = 1.0A, I _B = 100mA
Base-Emitter Turn On Voltage	V _{BE(on)}	_	1000	mV	$I_C = 1.0A, V_{CE} = 5.0V$

Notes: 7. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

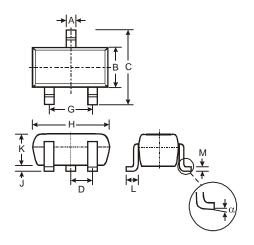


Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)



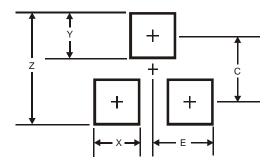


Package Outline Dimensions



	SOT323					
Dim	Min	Max	Тур			
Α	0.25	0.40	0.30			
В	1.15	1.35	1.30			
С	2.00	2.20	2.10			
D	-	-	0.65			
G	1.20	1.40	1.30			
Н	1.80	2.20	2.15			
J	0.0	0.10	0.05			
K	0.90	1.00	1.00			
L	0.25	0.40	0.30			
M	0.10	0.18	0.11			
α	0°	8°	-			
All	All Dimensions in mm					

Suggested Pad Layout



Dimensions	Value (in mm)			
Z	2.8			
Х	0.7			
Y	0.9			
С	1.9			
Е	1.0			



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